



Data Sheet

,TO-252,MOSFET-60V-12A P-Channel

Manufacturers ON Semiconductor, LLC

Package/Case TO-252

Product Type Transistors

RoHS Rohs

Lifecycle



Images are for reference only

Please submit RFQ for NTD2955G or Email to us: sales@ovaga.com We will contact you in 12 hours.



## **General Description**

This Power MOSFET is designed to withstand high energy in the Avalanche and Commutation Modes. Designed for low voltage, high speed switching applications in power supplies, converters, and power motor controls. These devices are particularly well suited for bridge circuits where diode speed and commutating safe operating areas are critical and offer an additional safety margin against unexpected voltage transients.

Features Application

Avalanche Energy Specified ONSEMI

IDSS and VDS(on) Specified at Elevated Temperature

Designed for Low Voltage, High Speed Switching Applications and to Withstand High Energy in the Avalanche and Commutation Modes

RoHS Compliant



**Related Products** 



NTR4003NT3G

ON Semiconductor, LLC

SOT-23



NTS2101PT1G
ON Semiconductor, LLC
SOT-323



NTMFS4C10NT1G
ON Semiconductor, LLC
SO-8FL



NTH4L020N120SC1
ON Semiconductor, LLC
TO-247



NTZD3155CT2G

ON Semiconductor, LLC
SOT-563-6



NTR5103NT1G

ON Semiconductor, LLC

SOT-23



NTHD4102PT1G

ON Semiconductor, LLC

ChipFET-8



NTGS3443T1G
ON Semiconductor, LLC
TSOP6